## **LISTING OF THE CLAIMS**

 (Previously Presented) A semiconductor polishing composition comprising: fumed silica, the semiconductor polishing composition being an aqueous dispersion solution of fumed silica,

wherein an increase rate of average particle diameter of fumed silica after a shake test for 10 days is 10% or less.

- 2. (Original) The semiconductor polishing composition of claim 1, wherein a content of the fumed silica is in a range of 10 to 30% by weight based on a total amount of the composition.
- 3. (Previously Presented) The semiconductor polishing composition of claim 1, wherein the average particle diameter of the fumed silica is in a range of 70 to 110 nm.
- 4. (Previously Presented) The semiconductor polishing composition of claim 1, wherein the semiconductor polishing composition is prepared by adding an acidic fumed silica dispersion solution to an alkali aqueous solution.
- 5. (Original) The semiconductor polishing composition of claim 4, wherein a pH of the alkali aqueous solution is in a range of 12 to 14.

U.S. Application No. 10/594,635 Atty. Docket No. 2691-000050/US

- 6. (Previously Presented) The semiconductor polishing composition of claim 2, wherein the average particle diameter of the fumed silica is in a range of 70 to 110 nm.
- 7. (Previously Presented) The semiconductor polishing composition of claim 2, wherein the semiconductor polishing composition is prepared by adding an acidic fumed silica dispersion solution to an alkali aqueous solution.
- 8. (Previously Presented) The semiconductor polishing composition of claim 3, wherein the semiconductor polishing composition is prepared by adding an acidic fumed silica dispersion solution to an alkali aqueous solution.
- 9. (Previously Presented) The semiconductor polishing composition of claim 6, wherein the semiconductor polishing composition is prepared by adding an acidic fumed silica dispersion solution to an alkali aqueous solution.
- 10. (Previously Presented) The semiconductor polishing composition of claim 7, wherein a pH of the alkali aqueous solution is in a range of 12 to 14.
- 11. (Previously Presented) The semiconductor polishing composition of claim 8, wherein a pH of the alkali aqueous solution is in a range of 12 to 14.
- 12. (Previously Presented) The semiconductor polishing composition of claim 9, wherein a pH of the alkali aqueous solution is in a range of 12 to 14.